LA8519M



# I/O Switch/Voice Signal-Processing IC for Cordless Telephones

# Overview

The LA8519M is a cordless telephone base unit IC that provides I/O switching, voice signal processing, and other functions. It integrates, on a single chip, crosspoint switch, power amplifier, electronic volume and tone control, microphone amplifier, speech network, and other functions.

# **Functions**

- · Speech network block
  - Impedance matching, 2-wire/4-wire converter, line driver, BN circuit network switching circuit, transmitter amplifier, BTL receiver amplifier, DTMF input, key tone input, receiver volume level switching, and power supply switching circuit.
- Audio signal-processing block
  - Power amplifier, electronic volume and tone control, preamplifier with ALC, voice level detection (VOX), beep tone input, ring tone (OSC) input, ring tone level switching, line volume level switching, microphone amplifier, crosspoint switch (10 × 9 point equivalent), and serial interface.

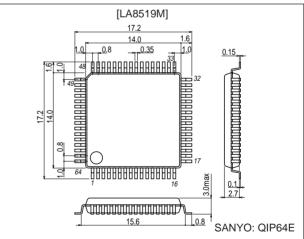
# **Features**

- Allows switching between two anti-sidetone networks (near terminal/far terminal) depending on the line current, and thus achieves excellent sidetone characteristics over a wide range of line currents.
- Built-in transmitter/receiver amplifier driver power supply switching circuit allows communication using extension without power from the telephone network.
- The receiver amplifier supports both ceramic receivers (BTL) and dynamic receiver (single).
- Built-in power amplifier (load: 8 to 32  $\Omega$ ): V\_{CC} = 5 V, R\_L = 8  $\Omega,$  Pomax = 200 mW
- The power amplifier signal path includes an electronic volume control (7 steps of about 3.8 dB each)
- Includes a 10-input/9-output crosspoint switch that provides mixing functions for easy implementation of systems that support a diverse range of signal path switching functions.

# **Package Dimensions**

Unit:mm

## 3159-QIP64E



- Any and all SANYO products described or contained herein do not have specifications that can handle applications that require extremely high levels of reliability, such as life-support systems, aircraft's control systems, or other applications whose failure can be reasonably expected to result in serious physical and/or material damage. Consult with your SANYO representative nearest you before using any SANYO products described or contained herein in such applications.
- SANYO assumes no responsibility for equipment failures that result from using products at values that exceed, even momentarily, rated values (such as maximum ratings, operating condition ranges, or other parameters) listed in products specifications of any and all SANYO products described or contained herein.

SANYO Electric Co., Ltd. Semiconductor Company TOKYO OFFICE Tokyo Bldg., 1-10, 1 Chome, Ueno, Taito-ku, TOKYO, 110-8534 JAPAN

# Specifications

# Maximum Ratings at $Ta = 25^{\circ}C$

Parameter	Symbol	Conditions	Ratings	Unit
	V <sub>CC</sub> max		15	V
Maximum supply voltage	V <sub>L</sub> max		15	V
Line current	I <sub>L</sub> max		130	mA
Allowable power dissipation	Pd max	$Ta \leq 70^{\circ}C$ (Mounted on a glass epoxy board: $120 \times 120 \times 1.6 \text{ mm}^3)$	1000	mW
Operating temperature	Topr		-20 to +70	°C
Storage temperature	Tstg		-40 to +150	°C

# Operating Conditions at $Ta = 25^{\circ}C$

Parameter	Symbol	Conditions	Ratings	Unit
Recommended supply voltage	V <sub>CC</sub>	Other than the speech network	5.0	V
Allowable operating supply voltage range	V <sub>CC</sub> op	Pin 17	4.5 to 6.5	V
Allowable operating supply voltage range	V <sub>CC</sub> oppwr	Pin 28	4.5 to 9.5	V

## **Electrical Characteristics**

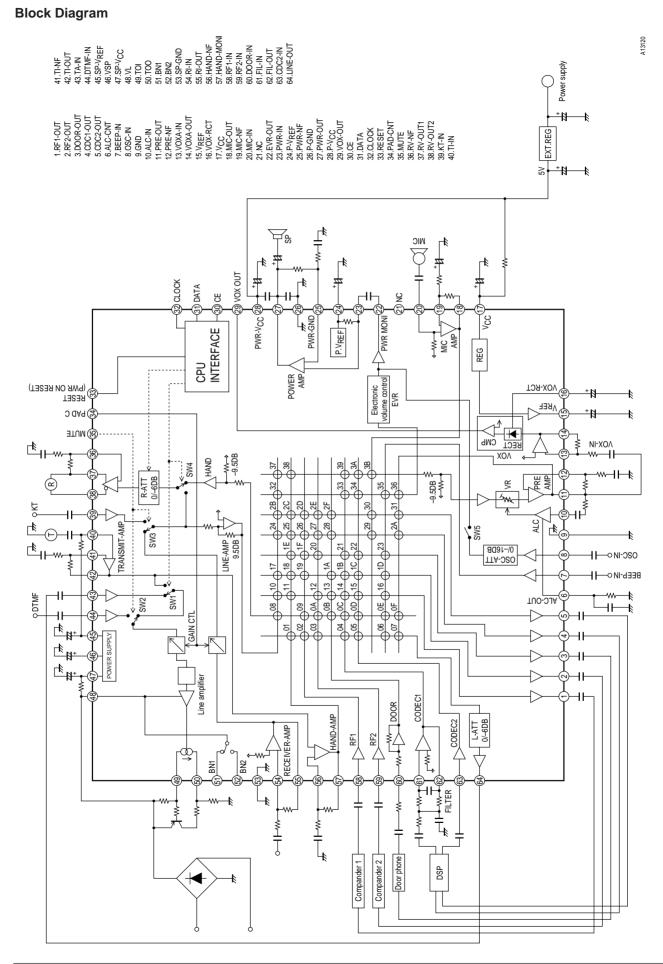
<b>D</b>				Ratings		unit
Parameter	Symbol	Conditions	min	typ	max	unit
[Speech Network Block] at Ta	= 25°C, Power s	upplied: V <sub>CC</sub> = 5 V, f <sub>IN</sub> = 1 kHz				1
Line voltage (20 mA, power supplied/power off)	V <sub>L</sub> 1	I <sub>L</sub> = 20 mA	3.3	3.8	4.3	V
Line voltage (50 mA, power supplied/power off)	V <sub>L</sub> 2	I <sub>L</sub> = 50 mA	4.5	5.2	6.0	V
Line voltage (120 mA, power supplied)	EV <sub>L</sub> 3	I <sub>L</sub> = 120 mA	7.1	8.5	9.9	V
Line voltage (120 mA, power off)	L <sub>V</sub> 3	I <sub>L</sub> = 120 mA	7.0	8.4	9.8	V
Transmitter gain (20 mA, power supplied)	EGt1	$I_L = 20 \text{ mA}, V_{IN} = -55 \text{ dBV}$	42.5	44.5	46.5	dB
Transmitter gain (20 mA, power off)	Gt1	$I_L = 20 \text{ mA}, V_{IN} = -55 \text{ dBV}$	42.3	44.3	46.3	dB
Transmitter gain (120 mA, power supplied/power off)	Gt2	I <sub>L</sub> = 120 mA, V <sub>IN</sub> = -55 dBV	38.3	40.3	42.3	dB
Receiver gain (20 mA, power supplied)	EGr1	$I_L = 20 \text{ mA}, V_{IN} = -20 \text{ dBV}$	-0.9	1.1	3.1	dB
Receiver gain (120 mA, power supplied)	EGr2	I <sub>L</sub> = 120 mA, V <sub>IN</sub> = -20 dBV	-7.4	-5.4	-3.4	dB
Receiver gain (20 mA, power off)	Gr1	$I_L = 20 \text{ mA}, V_{IN} = -20 \text{ dBV}$	-5.4	-3.4	-1.4	dB
Receiver gain (120 mA, power off)	Gr2	I <sub>L</sub> = 120 mA, V <sub>IN</sub> = -20 dBV	-8.7	-6.7	-4.7	dB
DTMF gain (20 mA, power supplied/power off)	Gmf1	$I_L = 20 \text{ mA}, V_{IN} = -30 \text{ dBV}$	27.7	29.7	31.7	dB
DTMF gain (120 mA, power supplied/power off)	Gmf2	I <sub>L</sub> = 120 mA, V <sub>IN</sub> = -30 dBV	23.6	25.6	27.6	dB
KT gain (power supplied)	EGkt	$I_L = 20 \text{ mA}/120 \text{ mA}, V_{IN} = -40 \text{ dBV}$	10.0	12.0	14.0	dB
KT gain (20 mA, power off)	Gkt1	$I_L = 20 \text{ mA}, V_{IN} = -40 \text{ dBV}$	5.8	7.8	9.8	dB
KT gain (120 mA, power off)	Gkt2	$I_L = 120 \text{ mA}, V_{IN} = -40 \text{ dBV}$	9.0	11.0	13.0	dB
Transmitter dynamic range (20 mA, power supplied/power off)	DRt1	I <sub>L</sub> = 20 mA, THD = 4%	2.5	5.6		Vp-p
Transmitter dynamic range (120 mA, power supplied/power off)	DRt2	I <sub>L</sub> = 120 mA, THD = 4%	4.5	7.7		Vp-p
Receiver dynamic range (power supplied)	EDRs	$I_L$ = 20 mA/120 mA, R <sub>L</sub> = 150 Ω, THD = 10%	0.5	1.5		Vp-p
Receiver dynamic range (20 mA, power off)	DRs1	$R_L$ = 150 Ω, $I_L$ = 20 mA, THD = 10%	0.3	0.55		Vp-p
Receiver dynamic range (120 mA, power off)	DRs2	$R_L$ = 150 Ω, $I_L$ = 120 mA, THD = 10%	0.5	1.4		Vp-p

Parameter	Symbol	Conditions		Ratings		unit
	-,		min	typ	max	
Receiver BTL dynamic range (power supplied)	EDRb	I <sub>L</sub> = 20 mA/120 mA, R <sub>L</sub> = 3 kΩ, THD = 10%	5	10		Vp-p
Receiver BTL dynamic range (20 mA, power off)	DRb1	$R_L = 3 \text{ k}\Omega, \text{ I}_L = 20 \text{ mA}, \text{ THD} = 10\%$	2	3.4		Vp-p
Receiver BTL dynamic range (120 mA, power off)	DRb2	$R_L$ = 3 kΩ, $I_L$ = 120 mA, THD = 10%	5	8.4		Vp-p
MUTE input high-level voltage (power supplied/power off)	V <sub>IH</sub>	I <sub>L</sub> = 20 mA to 120 mA	0.6 VSP			V
MUTE input low-level voltage (power supplied/power off)	V <sub>IL</sub>	I <sub>L</sub> = 20 mA to 120 mA	0		0.4	V
Transmitter PADC attenuation (power supplied/power off)	ΔGt	I <sub>L</sub> = 40 mA, pin 34: grounded through 24 $\Omega$		4.0		dB
Receiver PADC attenuation (power supplied/power off)	ΔGr	$I_L$ = 40 mA, pin 34: grounded through 24 $\Omega$		6.0		dB
Internal supply voltage (power supplied)	EV <sub>SP</sub>	I <sub>L</sub> = 20 mA/120 mA		4.75		V
Internal supply voltage (20 mA, power off)	V <sub>SP</sub> 1	I <sub>L</sub> = 20 mA		1.92		V
Internal supply voltage (120 mA, power off)	V <sub>SP</sub> 2	I <sub>L</sub> = 120 mA		4.74		V
Internal reference voltage (power supplied)	$ES-V_REF$	I <sub>L</sub> = 20 mA/120 mA		2.26		V
Internal reference voltage (20 mA, power off)	S-V <sub>REF</sub> 1	I <sub>L</sub> = 20 mA		0.79		V
Internal reference voltage (120 mA, power off)	S-V <sub>REF</sub> 2	I <sub>L</sub> = 120 mA		1.92		V
Voice Signal-Processing Bloc	k] at Ta = 25°C,	$V_{CC}$ = 5 V, f <sub>IN</sub> = 1 kHz, R <sub>L</sub> = 10 k $\Omega$				
(Crosspoint switch)						
Voltage gain	G <sub>SW</sub>	$V_{IN} = -13 \text{ dBV}$ , pin 58 input, pin 2 output	-2.5	-0.5	1.5	dB
Maximum input level	V <sub>IN</sub> max	THD = 1.5%	-13.5	-7.5		dBV
Output noise voltage	V <sub>NOSW</sub>	Rg = 620 Ω, 20 to 20 kHz		7.0	40	μVrm
(Preamplifier: input from the c	rosspoint switch)					
Voltage gain	VG <sub>C</sub>	$V_{IN} = -45 \text{ dBV}$	8.5	10.5	12.5	dB
Total harmonic distortion	THD	$V_{IN} = -20 \text{ dBV}$		0.26	1.0	%
ALC saturated output level	V <sub>OS</sub>	$V_{IN} = -20 \text{ dBV}$	93	115	137	mVrm
ALC range	ALCW	From the point the ALC circuit turns on to the point the THD reaches 1%.	15			dB
Output noise voltage	V <sub>NO</sub>	Rg = 620 Ω, 20 to 20 kHz		65	250	μVrm
(Microphone amplifier)				1	1	1
Voltage gain	VGm	$V_{IN} = -40 \text{ dBV}$	27.5	29.5	31.5	dB
Total harmonic distortion	THD	$V_{IN} = -40 \text{ dBV}$		0.05	1.0	%
Output noise voltage	V <sub>NO</sub>	$Rg = 620 \Omega$ , 20 to 20 kHz		65	250	μVrm
(Power amplifier)	110			1	1	
Voltage gain	VGp	R <sub>L</sub> = 8 Ω, V <sub>IN</sub> = -30 dBV	27.5	29.5	31.5	dB
Maximum output power	Po	$R_{\rm I} = 8 \Omega$ , THD = 10%	200	275		mW
Total harmonic distortion	THD	$V_{IN} = -30 \text{ dBV}$	200	0.8	1.5	%
Ripple rejection ratio	SVRR	$Rg = 620 \Omega$ , fr = 100 kHz, Vr = -20 dBV	40	50	1.0	dB
Output noise voltage	V <sub>NO</sub>	$Rg = 620 \Omega$ , 20 to 20 kHz		35	100	μVrm
(VOX)	۳NO	11g - 020 32, 20 10 20 KHZ		00	100	μνιιι
· · /		$V_{-} = 40  dP V_{-} P_{-} = 100  kO_{-}$		0.1	0.2	V
Sensitivity 1 low level	V <sub>OX</sub> L	$V_{IN} = -40 \text{ dBV}, \text{ R}_{L} = 100 \text{ k}\Omega$	4.0		0.3	
Sensitivity 2 high level	V <sub>OX</sub> H	$V_{IN} = -44 \text{ dBV}, \text{ R}_{L} = 100 \text{ k}\Omega$	4.8	4.95		V
(Electronic volume control)		I	0.0	0.0	4-	
Step width	Evrw		2.9	3.8	4.7	dB
(Attenuator)		I	1			
R-ATT attenuation	∆GR		5.4	6.4	7.4	dB
LINE-ATT attenuation	∆GL		4.6	5.6	6.6	dB
	ΔGO		13.1	14.6	16.1	dB

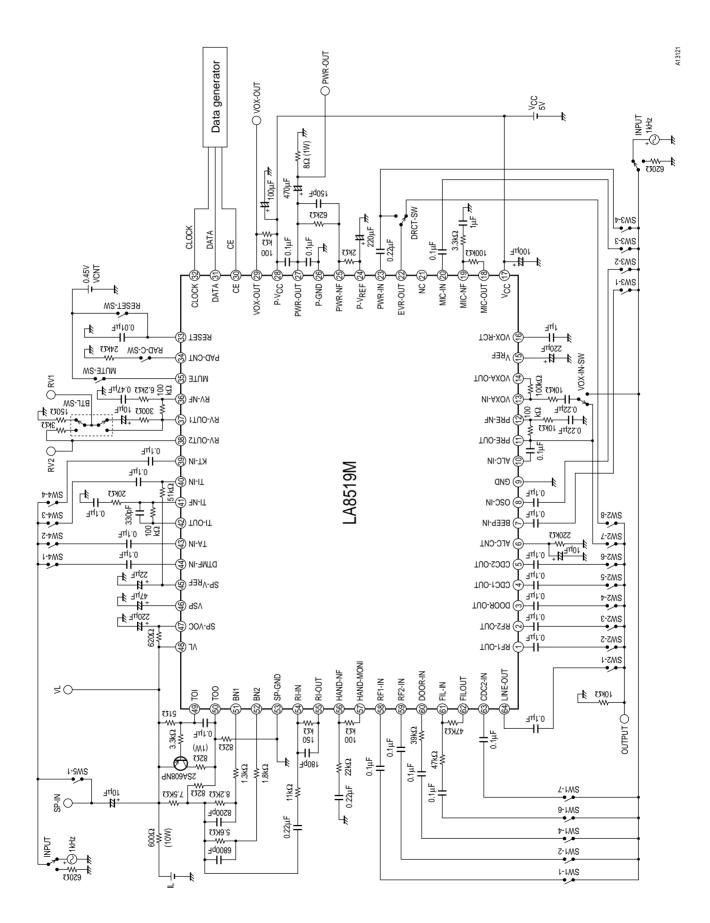
# LA8519M

Continued from preceding page.

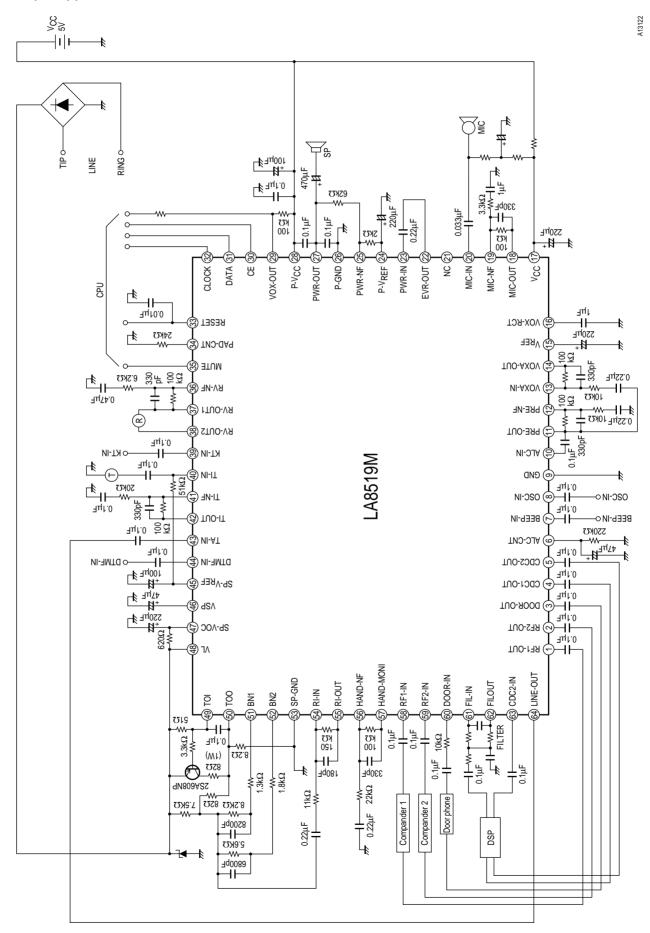
Deveryor	Complexel			Ratings		
Parameter	Symbol	Conditions	min	typ	max	unit
(V <sub>REF</sub> )						
Output voltage	V <sub>REF</sub>		2.07	2.27	2.47	V
(Serial Control)						
Clock frequency	Fck				500	kHz
Input signal high level	V <sub>H</sub>		2.3			V
Input signal low level	VL				1.0	V
(Power Supply Switching)						
Pin 17 voltage 1	Vch1	The voltage applied to pin 17 is valid.	3.5			V
Pin 17 voltage 2	Vch2	The voltage supplied from pin 48 is valid.			1.0	V
Quiescent current	Icco	With the power amplifier on		24	33.5	mA



## **Test Circuit Diagram**

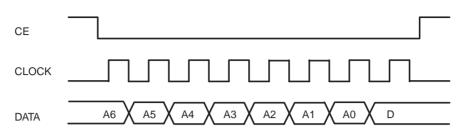


### **Sample Application Circuit**



### LA8519M

## Serial Data Format



A6 to A0  $\Rightarrow$  Sets the address of the crosspoint switch or control switch (hexadecimal  $\Rightarrow$  binary number)  $D \Rightarrow$ 

Sets the on/off state of the crosspoint switch or control switch.

(The switch is set to the on state when D is 1, and to the off state when 0.)

#### **Address Table**

Output Input	LINE	HAND	RF1	RF2	DOOR	CDC1	CDC2	EVR	PRE
LINE	—	08	10	17	_	24	2B	32	37
HAND	01	—	11	18	1E	25	2C	—	38
RF1	02	09	—	19	1F	26	2D	—	—
RF2	03	0A	12	_	20	27	2E	—	—
DOOR	—	0B	13	1A	—	28	2F	—	—
CDC1	04	0C	14	1B	21	—	_	33	39
CDC2	05	0D	15	1C	22	—	—	34	ЗA
MIC	—	—	—	_	—	29	30	—	3B
BEEP	06	0E	16	1D	23	—	_	35	—
PRE	07	0F	_	_	—	2A	31	36	—

#### Other addresses

Address No.		Mode			
00	Sets all crosspoint and control switch	es to the off state. *2			
3C	ALC control (D = 1: Off, D = 0: On)				
3D	Transmitter/receiver control (SW1 and	d SW4 in the block diagram) *1			
3E	OSC input (SW5) control (D = 1: On,	D = 0: Off)			
3F	Power amplifier control (D = 1: On, D	= 0: Off)			
40	Electronic volume control 0 dB	$\Rightarrow$ (Default value)			
41	Electronic volume control -4 dB				
42	Electronic volume control -8 dB				
43	Electronic volume control -12 dB	*2			
44	Electronic volume control -16 dB				
45	Electronic volume control -20 dB				
46	Electronic volume control -24 dB				
47	Electronic volume control -28 dB	Electronic volume control –28 dB			
7D	Line attenuator (L-ATT) setting (D = 1: -6 dB, D = 0: 0 dB)				
7E	Receiver attenuator (R-ATT) setting (D = 1: 0 dB, D = 0: -6 dB)				
7F	Oscillator attenuator (OSC-ATT) setti	ng (D = 1: 0 dB, D = 0: -16 dB)			

\* With address 3D set to the on state, SW1 is set to enable the transmitter amplifier output (pin 42) and SW4 is set to enable either the receiver amplifier output (pin 55) or the KT (pin 39) signal. If a voltage is not supplied to V<sub>CC</sub> (pin 17) (i.e. the power off state), SW1 and SW4 are set to the same states as when address 3D is set to the on state.

\*\* For addresses 00 and 40 to 47, the data D may be either 0 or 1.

Notes: 1. The receiver attenuator (R-ATT) is set to -6 dB at power on or after a reset (pin 33 set to low, or address 00 accessed).

2. The line attenuator (L-ATT) is set to 0 dB at power on or after a reset (pin 33 set to low, or address 00 accessed).

3. The oscillator attenuator (OSC-ATT) is set to -16 dB at power on or after a reset (pin 33 set to low, or address 00 accessed).

4. The electronic volume control is set to 0 dB at power on or after a reset (pin 33 set to low, or address 00 accessed).

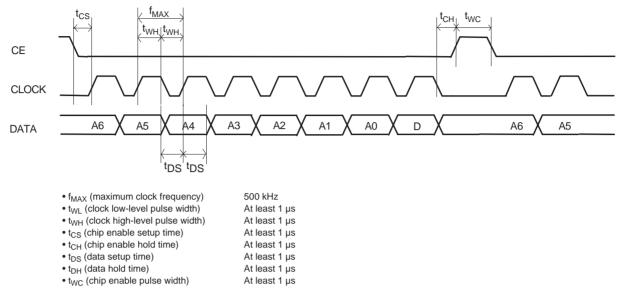
5. Addresses are expressed as hexadecimal numbers.

6. Since the LA8519M includes a power on reset function, all the crosspoint and control switches are reset to their default states when external power (pin 17: V<sub>CC</sub>) is applied.

7. Switches SW2 and SW3 in the block diagram are controlled by the MUTE pin (pin 35). The table lists the signals enabled by this pin.

MUTE pin (pin 35)	SW2	SW3
High/Open	Transmitter (pin 42) and TA-IN (pin 43)	Receiver (pin 55)
Low	DTMF pin (pin 44)	KT pin (pin 39)

## **Serial Data Timing**



Note: The control data must be input at least 400 ms after the supply voltage is applied to the  $V_{CC}$  pin (pin 17).

# **Pin Functions**

Pin No.	Pin	Notes	Equivalent circuit
1 2 3 4 5	RF1-OUT RF2-OUT DOOR-OUT CDC1-OUT CDC2-OUT	• These are the IC outputs.	$V_{REF}$ CP-SW $10 k\Omega$ $10 k\Omega$
6	ALC-CNT	• Adjusts the ALC time constants This pin can be used to adjust the ALC attack time and recovery time.	V <sub>cc</sub> 6
7 8 58 59 63	BEEP-IN OSC-IN RF1-IN RF2-IN CDC2-IN	<ul> <li>Beep tone amplifier input</li> <li>Oscillator amplifier input</li> <li>Compander 1 input</li> <li>Compander 2 input</li> <li>CDC2 amplifier input</li> </ul>	V <sub>CC</sub> V <sub>REF</sub> 3 (7) 58 59 63 7777 777 777 777 777
9	GND	Signal-processing system ground	
10	ALC-IN	<ul> <li>ALC input. The PRE output (pin 11) is input to this pin through a coupling capacitor. The ALC level can be adjusted by inserting a resistor in series.</li> </ul>	V <sub>CC</sub> V <sub>REF</sub> 24 kΩ 10 10 10 kΩ

Continued from preceding page.

Pin No.	Pin	Notes	Equivalent circuit
11 12	PRE-OUT PRE-NF	• Preamplifier output	V <sub>CC</sub> V <sub>REF</sub> (12) (12) (12) (12) (13) (14) (14) (14) (14) (14) (14) (14) (14
13 14	VOXA-IN VOXA-OUT	• VOX amplifier input • VOX amplifier output	V <sub>CC</sub> V <sub>REF</sub> (3) (3) (3) (3) (3) (3) (3) (3)
15	VREF	• Internal reference voltage output	2.25 V 2.25 V 5 kΩ 7/7 7/7
16	VOX-RCT	<ul> <li>VOX detection output. This circuit can also be used as a waveform shaping circuit by forcibly setting this pin to the high state.</li> </ul>	4.7 kΩ 4.7 kΩ 4.7 kΩ 4.7 kΩ 4.7 kΩ 4.7 kΩ 4.7 kΩ
17	V <sub>CC</sub>	• External power supply input. This voltage is supplied to the signal-processing system and V <sub>SP</sub> (pin 46).	

	D	N	
Pin No.	Pin	Notes	Equivalent circuit
18 19 20	MIC-OUT MIC-NF MIC-IN	<ul> <li>Microphone amplifier output</li> <li>Microphone amplifier minus input</li> <li>Microphone amplifier plus input</li> </ul>	V <sub>CC</sub> V <sub>RE</sub> 100 kΩ 20 100 kΩ 100 kΩ
21	NC	• Unused.	
22	EVR-OUT	• EVR amplifier output	
23 24 25 27	PWR-IN P-VREF PWR-NF PWR-OUT	<ul> <li>Power amplifier plus input</li> <li>Power amplifier reference voltage (about 4/9 × P-V<sub>CC</sub>)</li> <li>Power amplifier minus input</li> <li>Power amplifier output</li> </ul>	P. $V_{CC}$ 24 24 $15 \text{ k}\Omega$ 23 $40 \text{ k}\Omega$ 777
26	P-GND	Power system ground	
28	P-V <sub>CC</sub>	Power system power supply	
29	VOX-OUT	• VOX output This is an open-collector output.	

Pin No.	Pin	Notes	Equivalent circuit
30 31 32 33	CE DATA CLOCK RESET	<ul> <li>Chip enable input</li> <li>Data input</li> <li>Clock input</li> <li>Reset Power on reset.</li> </ul>	$\begin{array}{c} V_{cc} \\ 100 \text{ k}\Omega \\ \hline \\ 30 \\ \hline \\ 31 \\ 1 \text{ k}\Omega \\ \hline \\ 32 \\ \hline \\ 33 \\ \hline \\ 777 \\ 777 \\ \hline 777 \\ 777 \\ \hline 7777 \\ 777 \\ 777 \\ \hline 777 \\ 777 \\ 777 \\ 7777 \\ 77$
34	PAD C	<ul> <li>Pad control. The gain control based on line current and the BN switching operating current can be controlled by connecting this pin through a resistor to either ground or S-V<sub>CC</sub> (pin 47).</li> </ul>	34 4.7 kΩ S-V <sub>CC</sub> 34 22 kΩ S 777 777
35	MUTE	• Muting control. This pin switches the transmitted audio and DTMF signals in the transmitter system and the KT and received signals in the receiver system. (Switches SW2 and SW3 in the block diagram.) When low, the DTMF and KT signals are enabled.	V <sub>SP</sub> 50 kΩ 35 1 kΩ 777 777 777 777
36 37 38	RV-NF RV-OUT1 RV-OUT2	<ul> <li>Receiver amplifier noise figure connection</li> <li>Receiver amplifier 1 output</li> <li>Receiver amplifier 2 output</li> </ul>	

Pin No.	Pin	Notes	Equivalent circuit	
39	KT-IN	• Key tone input	V <sub>SP</sub> REF V <sub>SP</sub> V <sub>SP</sub> V <sub>SP</sub> V <sub>SP</sub>	
40 41 42	TI-IN TI-NF TI-OUT	<ul> <li>Transmitter input amplifier plus input. Since no bias voltage is applied internally, a bias voltage must be applied through a resistor from the REF pin (pin 61).</li> <li>Transmitter input amplifier minus input</li> <li>Transmitter input amplifier output</li> </ul>		
43	TA-IN	• Input for the line output	V <sub>SP</sub> REF 40 kΩ 43 43 40 kΩ 177 177	
44	DTMF-IN	• DTMF input	V <sub>SP</sub> REF V <sub>SP</sub> V <sub>SP</sub>	

Pin No.	Pin	Notes	Equivalent circuit
45	REF	• Speech network system internal reference voltage output. When the V <sub>CC</sub> (pin 17) voltage is over 3.5 V, the reference voltage is output from V <sub>REF</sub> (pin 15). When the V <sub>CC</sub> voltage is under 1.2 V, a voltage of about (2/5) × V is output.	V <sub>SP</sub> 15 kΩ 45 10 kΩ 777 777 777 777 777
46	VSP	• Speech network system internal power supply. A voltage of about 0.3 V less than the voltage applied to V <sub>CC</sub> is output when the V <sub>CC</sub> (pin 17) voltage is over 3.5 V. When the V <sub>CC</sub> voltage is under 1.2 V, a voltage of about 0.3 V less than the S-V <sub>CC</sub> (pin 47) voltage is output.	
47	S-V <sub>CC</sub>	$\bullet$ Speech network system power supply. When the $V_{CC}$ voltage is under 1.2 V, power is supplied to $V_{SP}$ (pin 46) based on the line power.	
48 49 50	VL TOI TOO	<ul> <li>Line current input and line voltage</li> <li>Current input for the transmitter output current</li> <li>Transmitter output current output</li> </ul>	48 777 49 49 6.2 kΩ 100 Ω
51 52	BN1 BN2	<ul> <li>First BN switching control input</li> <li>Second BN switching control input Connect these inputs when two balancing networks are used. When unused, leave these pins open.</li> </ul>	
53	SP-GND	Speech network system ground	
54 55	RI-IN RI-OUT	<ul> <li>Receiver input amplifier minus input</li> <li>Receiver input amplifier output</li> </ul>	55 TTT TTT TTT TTT

Pin No.	Pin	Notes	Equivalent circuit	
56 57	HAND-NF HAND-MONI	• Handset amplifier minus input • Handset amplifier output		
60	DOOR-IN	• Door phone input	VREF         Vcc           60         777	
61 62	FIL-IN FIL-OUT	• FIL amplifier input • FIL amplifier output		
64	LINE-OUT	• Line amplifier output	V <sub>CC</sub> V <sub>CC</sub> 0 κΩ 10 κΩ	

## **Usage Notes**

Speech Network Circuit Block

• External driver transistor

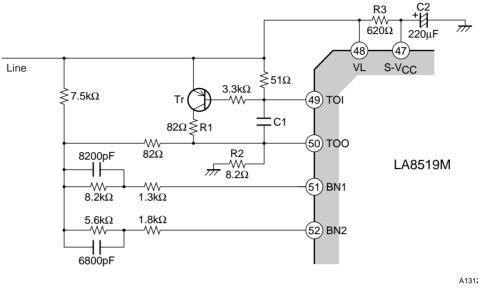


Figure 1

A13123

Since the IC includes a built-in power amplifier, due to the allowable power dissipation limits, include a heat dissipation transistor as shown in figure 1, and dissipate the circuit current outside the IC. Set the allowable power dissipation for R1 and R2 according to the maximum expected circuit current. (The values shown are for reference purposes only.)

Note: If oscillation occurs due to the load state between VL and ground, insert the capacitor C1 (about 0.1  $\mu$ F) shown in the figure.

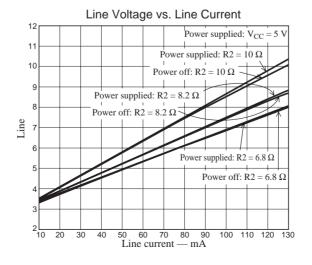
• Changing the DC resistance

The DC resistance can be modified by using a variable resistor for R2 in figure 1. (See the figure below.) Note: Note that changing R2 will also change the transmitter gain and the balancing network conditions.

• Determining the AC impedance

The AC impedance is basically determined by R3 (620  $\Omega$ ) and C2 (220  $\mu$ F) shown in figure 1 above page. Since in actual operation there will be other AC loads in addition to the speech network, adjust the total AC impedance for the whole system in combination with the speech network impedance.

Note: Note that if R3 is changed, the DC resistance will change as well.



## • Anti-sidetone network

The LA8519M can switch between two anti-sidetone networks, one for the near terminal and one for the far terminal, depending on the circuit current. (See figure 1 for the connections used.) The switching point can be changed by connecting PADC (pin 34) through a resistor to either ground or S-V<sub>CC</sub> (pin 47).

If only one anti-sidetone network is used, short pin 51 to pin 52 as shown in figure 2. (The component values shown are for reference purposes only.)

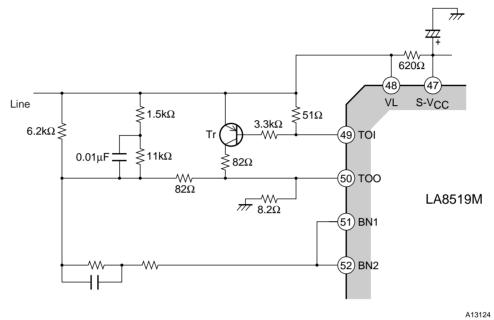
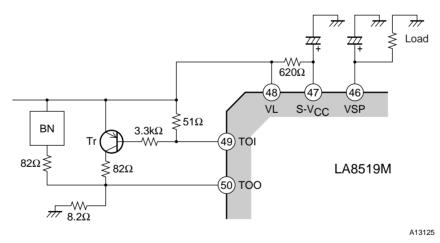


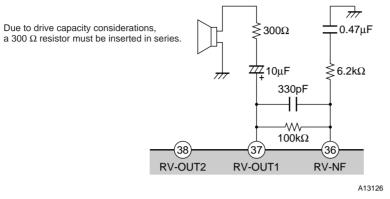
Figure 2

• Line voltage VL DC characteristics when V<sub>CC</sub> is not applied (Values shown are for reference purposes only.)

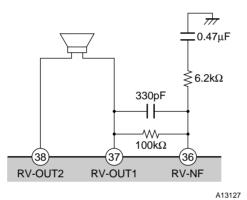


The slope of the DC characteristics when  $V_{CC}$  is not applied can be increased without changing the DC characteristics when  $V_{CC}$  is applied by applying a load to  $V_{SP}$  (pin 46).

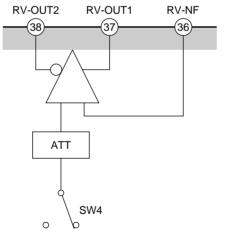
- Receiver amplifier application circuits
- (1) When a dynamic receiver is used (Values shown are for reference purposes only.)



(2) When a ceramic receiver is used (Values shown are for reference purposes only.)

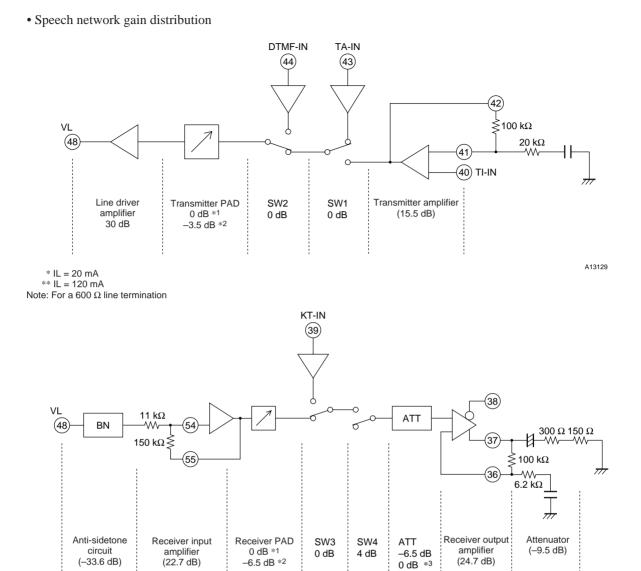


• Receiver attenuator



A13128

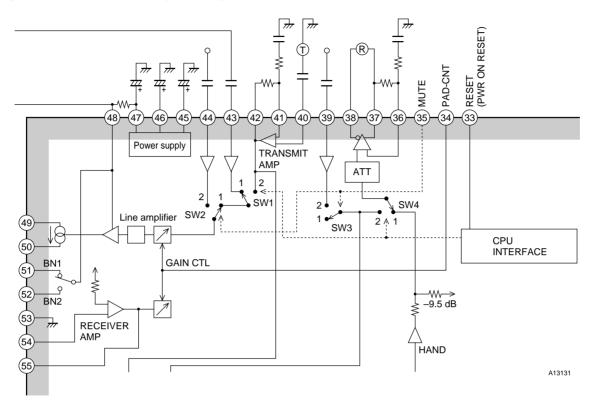
Normally, the receiver attenuator is set to -6 dB. It can be set to 0 dB by setting address 7E to the on state with a serial data transfer.



A13130

\* IL = 20 mA
\*\* IL = 120 mA
\*\*\* When address 7E is set to the on state with a serial data transfer.
Notes: 1. The gain values are rough values, and should be seen as target values during the design process.
2. Values in parentheses can be modified by external components.

• Speech network internal analog switch operation



Note: Switches SW2 and SW3 are controlled by the MUTE pin (pin 35). Switches SW1 and SW4 are controlled by address 3D as set by serial data transfers. Note that switches SW2 and SW3 operate together, as do switches SW1 and SW4.

#### SW1 and SW4 Operation

State	SW1	SW4
Power supplied (initial state)	1	1
Address 3D	2	2
Power off	2	2

Note: When the power is off, SW1 and SW4 go to the "2" positions, and their states cannot be changed.

#### SW2 and SW3 Operation

Pin 35 (MUTE)	SW2	SW3
High	1	1
Low	2	2

Note: SW2 and SW3 operate as described above regardless of the power supplied/off state.

• Line amplifier attenuator

Normally, the line attenuator is set to 0 dB. It can be set to -6 dB by setting address to 7D and mode to D = 1 with a serial data transfer.



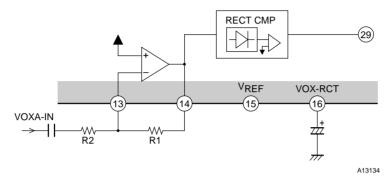
• Oscillator amplifier attenuator

Normally, the oscillator amplifier attenuator is set to -16 dB. It can be set to 0 dB by setting address to 7F and mode to D = 1 with a serial data transfer.

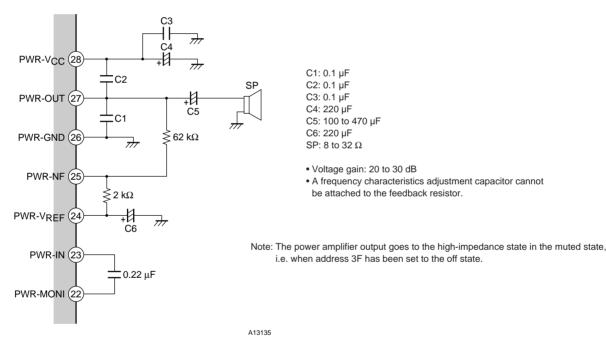


#### VOX circuit

- (1) The VOX circuit detects whether there is conversation or not. When the signal level in the VOXA input block (when the application constants in the application circuit diagram are used) becomes over about -42 dBV, the VOX output pin (pin 29) goes low. The detection level can be set by setting the gain of the VOX input amplifier with resistors R1 and R2.
- (2) This circuit can be used as a waveform shaping circuit if VOX-RCT (pin 16) is connected to V<sub>CC</sub>, i.e. if pin 16 is set to the high level. Thus this circuit can also be used to recognize a 400 Hz beep tone. In this mode, there is no need to connect a capacitor to pin 16.



• Power amplifier circuit applications (The component values are for reference purposes only.)



· Power amplifier phase compensation capacitors

Of the external components, the capacitors C1 between pin 27 (output) and pin 26 (ground) and C2 between pin 27 and pin 28 ( $V_{CC}$ ) are power amplifier phase compensation capacitors. If these components are separated from their pins in the PCB layout, their phase compensation effect may be reduced and high-frequency oscillation may occur.

We therefore strongly recommend using a layout in which the capacitors C1 and C2 are located as close as possible to their respective IC pins. In particular, C1, which is connected to ground, should be given priority in positioning close to the IC. Note that phase compensation not with capacitors alone, but with series resistors (on the order of 1 to 2.2  $\Omega$ ) inserted is also possible. While this can increase the phase compensation effect, since it increases the parts count, we recommend using capacitors only. However, we do recommend phase compensation with resistors inserted if, due to the details of the layout, the power amplifier is subject to oscillation.

Also note that the ceramic capacitor C3 between pins 26 and 28 has only a minimal phase compensation effect on normal power amplifiers, so is not required. However, there are cases where it does have a large effect due to the pattern layout, so we recommend creating a dummy pattern for this capacitor and handling it as a reserve component.

• Power amplifier VREF (pin 24) line

Pin 24 is the reference voltage pin for the power amplifier, and is connected to pin 23 (the input) by an internal bias resistor. This means that pin 24 is part of the power amplifier plus input line system. If this line is affected by the power amplifier output or the  $V_{CC}$  line, the resultant positive feedback can cause oscillation.

Therefore, if at all possible, the pin 24 line should not be routed around other lines. If it must be routed around other lines, do not rout it adjacent to output or  $V_{CC}$  lines, but rout it adjacent to ground lines to prevent interference.

• LA8519M ground line rerouting (See the figure on the next page.)

The LA8519M circuit blocks can be classified into three systems: (1) power amplifier, (2) speech network system, and (3) crosspoint switch and other small-signal processing systems. Since the IC itself, naturally, has a three-block structure, each block has independent  $V_{CC}$  and ground pins. The best possible ground system design, is for external components that are connected to ground to be connected to the ground for the block to which they belong, and for the pattern to be formed so that these three lines are independent and connect to the ground of the power supply (regulator) that is the reference.

However, since there are limitations on the area available on the printed circuit board, there are cases where a single line is connected to the reference ground. In this case, ground lines must be routed so that the ground lines that carry larger currents (power amplifier and line connection blocks) are closer to the power supply ground (and thus have a lower impedance)than ground lines for circuits with a lower current drain.

If the large currents used by the power amplifier or other high-current system flow in the ground lines that handle the smaller currents from small-signal system or other low-current system, a loop may be formed and low band oscillation may occur.

Therefore we recommend that the ground lines are designed, as described above, so that lines in which large currents flow are routed closest to the power supply ground.

IC Usage Notes

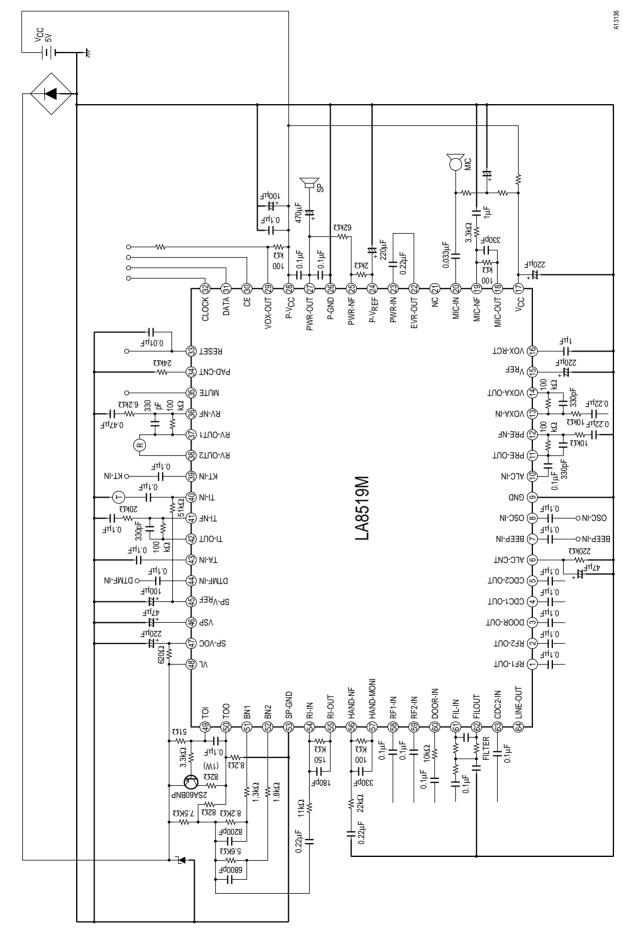
1. If the LA8519M is used in the vicinity of its maximum ratings, even slight variations in operating conditions may result in the maximum ratings being exceeded. Since this can lead to damage to or destruction of the device, provide adequate margin in the fluctuations in the supply voltage and other parameters, and do not allow the maximum ratings to be exceeded.

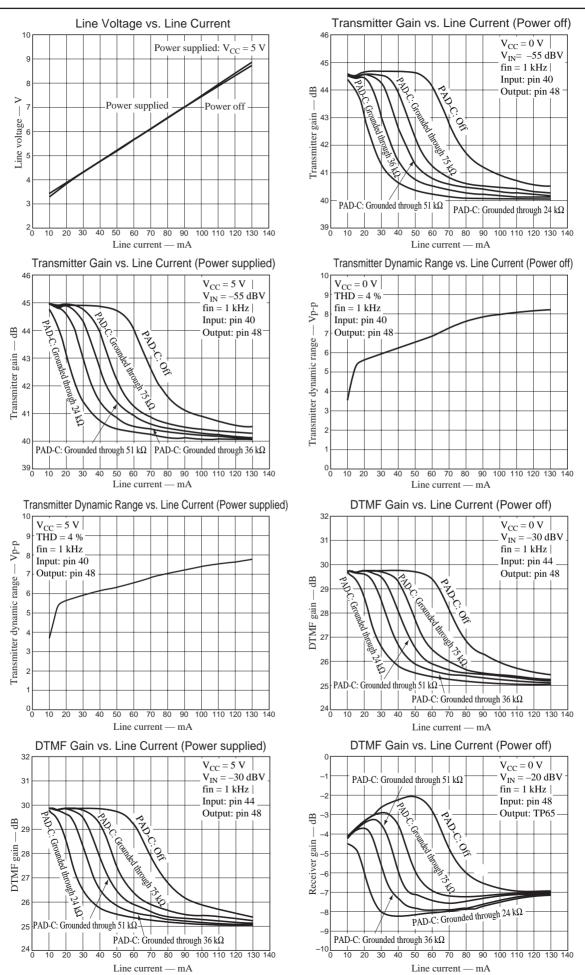
2. Pin shorting

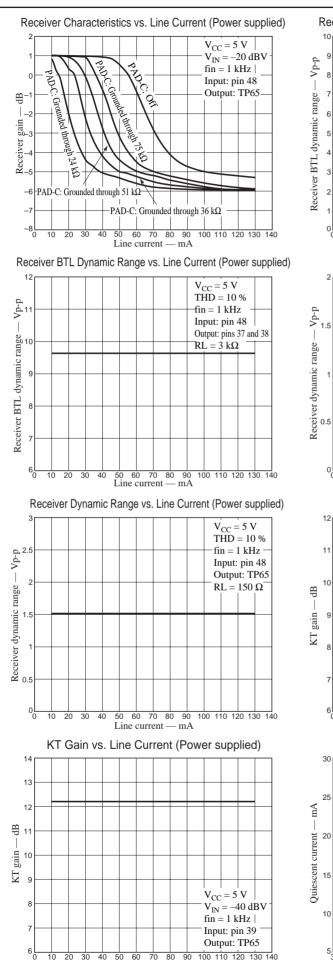
If the LA8519M is left with output loads shorted for extended periods, it may be damaged or destroyed. Always use this device in a manner such that output loads are never shorted.

## LA8519M

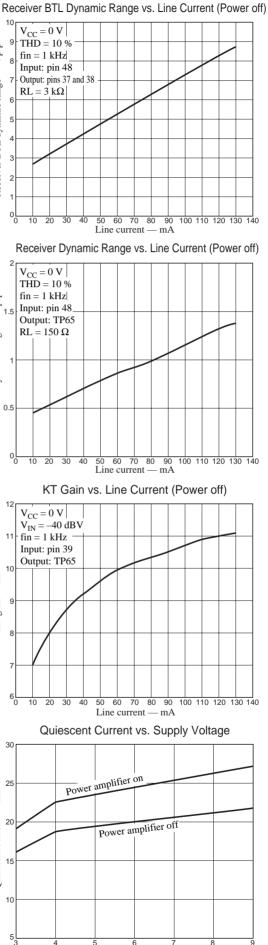
## **Ground Line Routing**



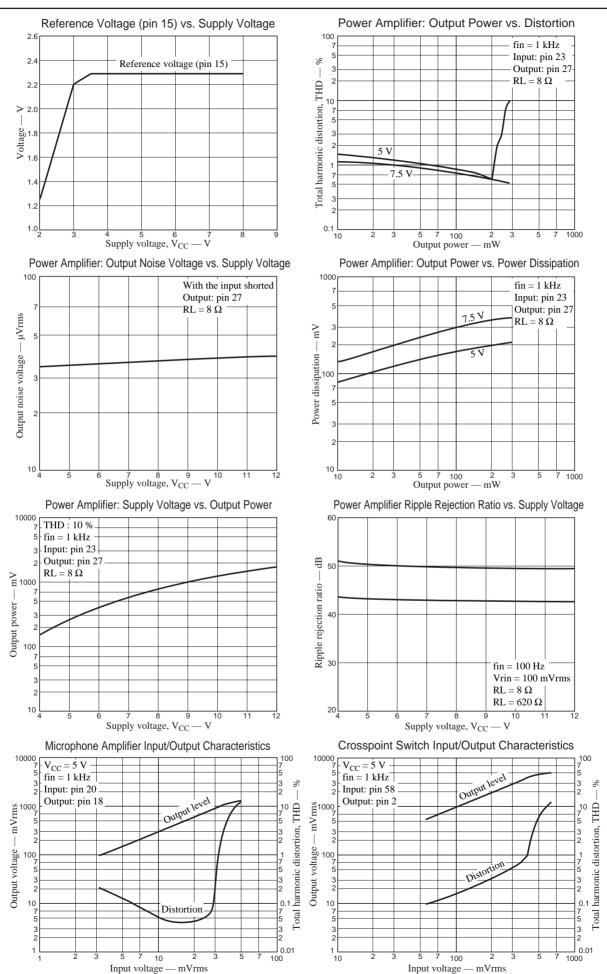


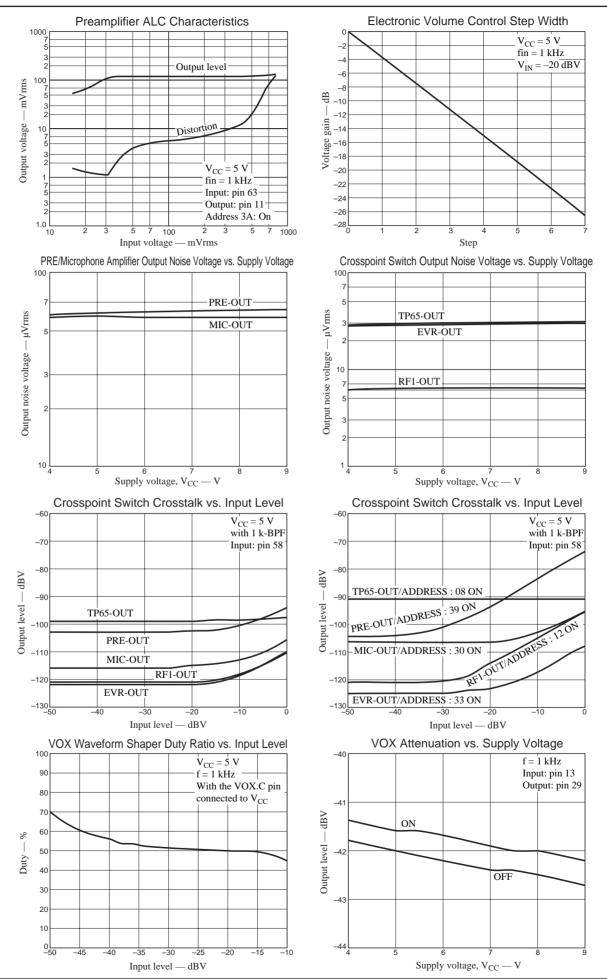


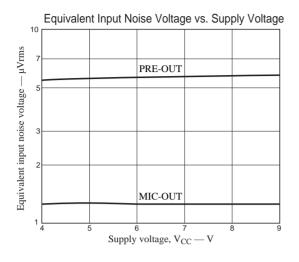
Line current — mA



Supply voltage, V<sub>CC</sub> – V







- Specifications of any and all SANYO products described or contained herein stipulate the performance, characteristics, and functions of the described products in the independent state, and are not guarantees of the performance, characteristics, and functions of the described products as mounted in the customer's products or equipment. To verify symptoms and states that cannot be evaluated in an independent device, the customer should always evaluate and test devices mounted in the customer's products or equipment.
- SANYO Electric Co., Ltd. strives to supply high-quality high-reliability products. However, any and all semiconductor products fail with some probability. It is possible that these probabilistic failures could give rise to accidents or events that could endanger human lives, that could give rise to smoke or fire, or that could cause damage to other property. When designing equipment, adopt safety measures so that these kinds of accidents or events cannot occur. Such measures include but are not limited to protective circuits and error prevention circuits for safe design, redundant design, and structural design.
- In the event that any or all SANYO products (including technical data, services) described or contained herein are controlled under any of applicable local export control laws and regulations, such products must not be exported without obtaining the export license from the authorities concerned in accordance with the above law.
- No part of this publication may be reproduced or transmitted in any form or by any means, electronic or mechanical, including photocopying and recording, or any information storage or retrieval system, or otherwise, without the prior written permission of SANYO Electric Co., Ltd.
- Any and all information described or contained herein are subject to change without notice due to product/technology improvement, etc. When designing equipment, refer to the "Delivery Specification" for the SANYO product that you intend to use.
- Information (including circuit diagrams and circuit parameters) herein is for example only; it is not guaranteed for volume production. SANYO believes information herein is accurate and reliable, but no guarantees are made or implied regarding its use or any infringements of intellectual property rights or other rights of third parties.

This catalog provides information as of October, 2000. Specifications and information herein are subject to change without notice.